Analog Power AM4533C

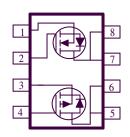
P & N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$ $I_D(A)$				
20	$40 @ V_{GS} = 2.5V$	6.0			
20	$31 @ V_{GS} = 4.5V$	6.9			
-20	$80 @ V_{GS} = -2.5V$	-4.2			
	$52 @ V_{GS} = -4.5V$	-5.2			

- $\hbox{ Low $r_{DS(on)}$ provides higher efficiency and} \\ \hbox{ extends battery life}$
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	N-Channel	P-Channel	Units	
Drain-Source Voltage		V_{DS}	20	-20	V	
Gate-Source Voltage			±8	±8	V	
	T _A =25°C	T_	6.9	-5.2		
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1_{D}	5.4	-6.8	A	
Pulsed Drain Current ^b			20	-20		
Continuous Source Current (Diode Conduction) ^a			1.3	-1.3	A	
D : a	$T_A=25^{\circ}C$	D	2.1	2.1	W	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	I D	1.3	1.3	Į VV	
Operating Junction and Storage Temperature Range			-55 to	°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum Units				
M	t <= 10 sec	D	62.5	°C/W		
Maximum Junction-to-Ambient ^a	Steady-State	$ m R_{\theta JA}$	110	°C/W		

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
n d	G 1 1		Limits				
Parameter	Symbol	Test Conditions	Ch	Min	Тур	Max	Unit
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{GS} = V_{DS}$, $I_{D} = 250 \text{ uA}$	N	0.4			V
Gate-Tilleshold Voltage	V GS(th)	$V_{GS} = V_{DS}$, $I_{D} = -250 \text{ uA}$	P	-0.4			
Gate-Body Leakage	I_{GSS}	$V_{GS} = -8 \text{ V}, V_{DS} = 0 \text{ V}$	P			±100	nA
Gate-Body Leakage	1GSS	$V_{GS} = 8 \text{ V}, V_{DS} = 0 \text{ V}$	N			±100	IIA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$	P			-1	uA
Zero Gate Voltage Drain Current	¹ DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$	N			1	uA
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	N	20			A
On-State Drain Current	¹ D(on)	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	P	-20			A
		VGS = 4.5 V, ID = 6.9 A	N			31	
Drain-Source On-Resistance ^A	r	VGS = 2.5 V, ID = 6 A	19			40	$_{ m m}\Omega$
Drain-Source On-Resistance	$r_{\mathrm{DS(on)}}$	VGS = -4.5 V, ID = -5.2 A	Р			52	ms2
		VGS = -2.5 V, ID = -4.2 A	Р			80	
E 1.T 1 4 A	g	$V_{DS} = 15 \text{ V}, I_D = 6.9 \text{ A}$	N		25		S
Forward Tranconductance ^A	g_{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -5.2 \text{ A}$	P		10		
Dynamic							
Total Gate Charge	Q_{g}		N		6.0		пС
Total Gate Charge	Qg	N-Channel	P		25		
Gate-Source Charge	Q_{gs}	V_{DS} =15V, V_{GS} =4.5V, I_{D} =6.9A	N		1.0		
Gate-Source Charge	≺gs	P-Channel	P		2.4		IIC
Gate-Drain Charge	Q _{gd} VDS=-15V, VGS=-4.5V, ID=-5.2A N		1.5				
Gute Bruin Charge	≺ga	₹gd	P		3.9		
Turn-On Delay Time	$t_{d(on)}$		N		7.4		1
Turn on Belly Time	cd(on)	N-Chaneel	P		7.6		
Rise Time	t _r	$V_{DD}=15V$, $VGS=4.5V$, $ID=1A$,	N		4		
Tuse Time	٠,	$R_{\text{GEN}}=6\Omega$,	P		6.8		nS
Turn-Off Delay Time	$t_{d(off)}$	P-Channel	N		22.2	<u> </u>	
	-d(011)	VDD=-15V, VGS=-4.5V, ID=-1A RGEN= 6Ω	P		33.6		
Fall-Time	t_{f}	KGEN-022	N		3.6		
Tan Tine	-1		P		23.2		

Notes

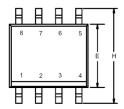
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

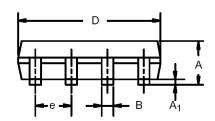
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Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INCHES		
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	

